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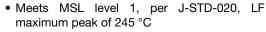
Vishay Semiconductors

# High Voltage Surface Mount Input Rectifier Diode, 10 A



PRIMARY CHARACTERISTICS						
I <sub>F(AV)</sub> 10 A						
$V_{R}$	800 V, 1000 V, 1200 V					
V <sub>F</sub> at I <sub>F</sub>	1.1 V					
I <sub>FSM</sub>	160 A					
T <sub>J</sub> max.	150 °C					
Package	D <sup>2</sup> PAK (TO-263AB)					
Circuit configuration	Single					

#### **FEATURES**





- Glass passivated pellet chip junction
- Designed and qualified according to JEDEC®-JESD 47
- Material categorization: for definitions of compliance please see <a href="https://www.vishay.com/doc?99912"><u>www.vishay.com/doc?99912</u></a>

#### **APPLICATIONS**

- Input rectification
- Vishay switches and output rectifiers which are available in identical package outlines

#### **DESCRIPTION**

The VS-10ETS..S-M3 rectifier series has been optimized for very low forward voltage drop, with moderate leakage. The glass passivation technology used has reliable operation up to 150 °C junction temperature.

OUTPUT CURRENT IN TYPICAL APPLICATIONS								
APPLICATIONS	SINGLE-PHASE BRIDGE	THREE-PHASE BRIDGE	UNITS					
Capacitive input filter T <sub>A</sub> = 55 °C, T <sub>J</sub> = 125 °C common heatsink of 1 °C/W	12.0	16.0	А					

MAJOR RATINGS AND CHARACTERISTICS									
SYMBOL	CHARACTERISTICS	VALUES	UNITS						
I <sub>F(AV)</sub>	Sinusoidal waveform	10	Α						
V <sub>RRM</sub>		800 to 1200	V						
I <sub>FSM</sub>		160	Α						
V <sub>F</sub>	10 A, T <sub>J</sub> = 25 °C	1.1	V						
TJ		-40 to +150	°C						

VOLTAGE RATINGS									
PART NUMBER	V <sub>RRM</sub> , MAXIMUM PEAK REVERSE VOLTAGE V	V <sub>RSM</sub> , MAXIMUM NON-REPETITIVE PEAK REVERSE VOLTAGE V	I <sub>RRM</sub> AT 150 °C mA						
VS-10ETS08S-M3	800	900							
VS-10ETS10S-M3	1000	1100	0.5						
VS-10ETS12S-M3	1200	1300							

ABSOLUTE MAXIMUM RATINGS								
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS				
Maximum average forward current	I <sub>F(AV)</sub>	T <sub>C</sub> = 105 °C, 180° conduction half sine wave	10					
Maximum peak one cycle	1	10 ms sine pulse, rated V <sub>RRM</sub> applied	135	Α				
non-repetitive surge current	I <sub>FSM</sub>	10 ms sine pulse, no voltage reapplied	160					
Maximum I <sup>2</sup> t for fusing	I <sup>2</sup> t	10 ms sine pulse, rated V <sub>RRM</sub> applied	91					
Maximum i-t for fusing	1-1	10 ms sine pulse, no voltage reapplied	130 A <sup>2</sup> s					
Maximum I <sup>2</sup> √t for fusing	I <sup>2</sup> √t	t = 0.1 ms to 10 ms, no voltage reapplied	1290	A <sup>2</sup> √s				

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ELECTRICAL SPECIFICATIONS									
PARAMETER SYMBOL TEST CONDITIONS VALUES UNITS									
Maximum forward voltage drop	$V_{FM}$	10 A, T <sub>J</sub> = 25 °C	1.1	V					
Forward slope resistance	r <sub>t</sub>	T <sub>.1</sub> = 150 °C	20	mΩ					
Threshold voltage	V <sub>F(TO)</sub>	1J = 150 C	0.82	V					
Maximum rayaraa laakaga aurrant		T <sub>J</sub> = 25 °C	\/ - rotod \/	0.05	mΛ				
Maximum reverse leakage current	IRM	T <sub>J</sub> = 150 °C	$V_R$ = rated $V_{RRM}$	0.50	mA				

THERMAL - MECHANICAL SPECIFICATIONS								
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS				
Maximum junction and storage temperature range	T <sub>J</sub> , T <sub>Stg</sub>		-40 to +150	°C				
Maximum thermal resistance, junction to case	R <sub>thJC</sub>	DC operation	2.5	°C/W				
Maximum thermal resistance, junction to ambient (PCB mount)	R <sub>thJA</sub> (1)		62	C/VV				
Approximate weight			2	g				
Approximate weight			0.07	OZ.				
			10ET	S08S				
Marking device		Case style D <sup>2</sup> PAK (TO-263AB)	10ETS10S					
			10ET	S12S				

#### Note

<sup>(1)</sup> When mounted on 1" square (650 mm²) PCB of FR-4 or G-10 material 4 oz. (140 µm) copper 40 °C/W. For recommended footprint and soldering techniques refer to application note #AN-994

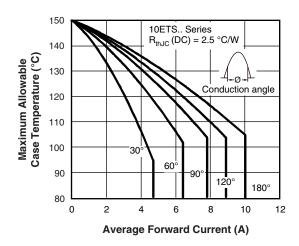


Fig. 1 - Current Rating Characteristics

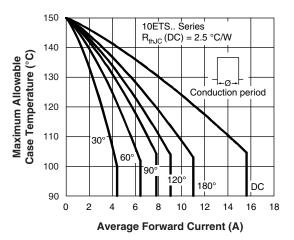


Fig. 2 - Current Rating Characteristics

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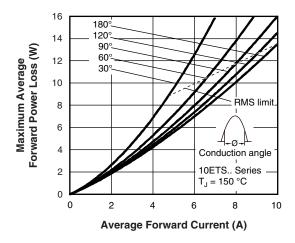


Fig. 3 - Forward Power Loss Characteristics

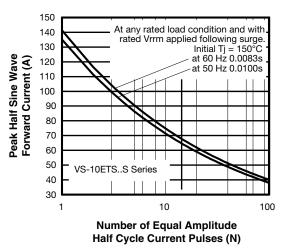


Fig. 5 - Maximum Non-Repetitive Surge Current

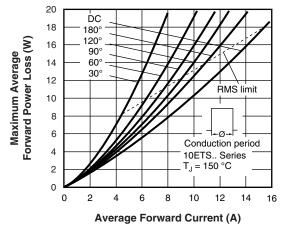


Fig. 4 - Forward Power Loss Characteristics

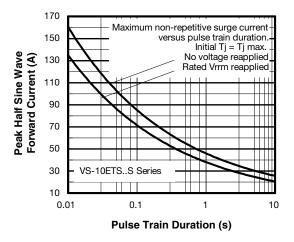


Fig. 6 - Maximum Non-Repetitive Surge Current

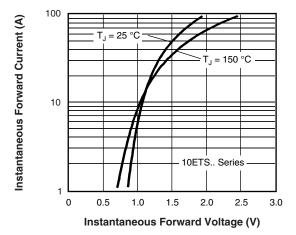


Fig. 7 - Forward Voltage Drop Characteristics

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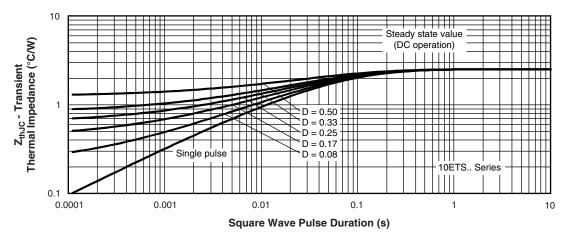
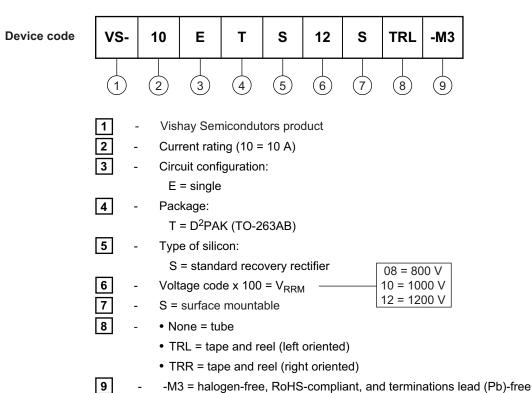


Fig. 8 - Thermal Impedance Z<sub>thJC</sub> Characteristics

#### **ORDERING INFORMATION TABLE**





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ORDERING INFORMATION (Example)								
PREFERRED P/N	QUANTITY PER TUBE	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION					
VS-10ETS08S-M3	50	1000	Antistatic plastic tube					
VS-10ETS08STRR-M3	800	800	13" diameter reel					
VS-10ETS08STRL-M3	800	800	13" diameter reel					
VS-10ETS10S-M3	50	1000	Antistatic plastic tube					
VS-10ETS10STRR-M3	800	800	13" diameter reel					
VS-10ETS10STRL-M3	800	800	13" diameter reel					
VS-10ETS12S-M3	50	1000	Antistatic plastic tube					
VS-10ETS12STRR-M3	800	800	13" diameter reel					
VS-10ETS12STRL-M3	800	800	13" diameter reel					
VS-10ETS08S-M3	50	1000	Antistatic plastic tube					

LINKS TO RELATED DOCUMENTS						
Dimensions	www.vishay.com/doc?96164					
Part marking information	www.vishay.com/doc?95444					
Packaging information	www.vishay.com/doc?96424					



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### D<sup>2</sup>PAK

#### **DIMENSIONS** in millimeters and inches



SYMBOL	MILLIM	ETERS	INC	HES	NOTES	NOTES	SYMBOL	MILLIM	ETERS	INC	HES	NOTES
STWIBOL	MIN.	MAX.	MIN.	MAX.	NOTES		STIVIBUL	MIN.	MAX.	MIN.	MAX.	NOTES
Α	4.06	4.83	0.160	0.190			D1	6.86	8.00	0.270	0.315	3
A1	0.00	0.254	0.000	0.010			E	9.65	10.67	0.380	0.420	2, 3
b	0.51	0.99	0.020	0.039			E1	7.90	8.80	0.311	0.346	3
b1	0.51	0.89	0.020	0.035	4		е	2.54	BSC	0.100	BSC	
b2	1.14	1.78	0.045	0.070			Н	14.61	15.88	0.575	0.625	
b3	1.14	1.73	0.045	0.068	4		L	1.78	2.79	0.070	0.110	
С	0.38	0.74	0.015	0.029			L1	-	1.65	-	0.066	3
c1	0.38	0.58	0.015	0.023	4		L2	1.27	1.78	0.050	0.070	
c2	1.14	1.65	0.045	0.065			L3	0.25	BSC	0.010	BSC	
D	8.51	9.65	0.335	0.380	2		L4	4.78	5.28	0.188	0.208	

#### Notes

- (1) Dimensioning and tolerancing per ASME Y14.5 M-1994
- (2) Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body
- (3) Thermal pad contour optional within dimension E, L1, D1 and E1
- (4) Dimension b1 and c1 apply to base metal only
- (5) Datum A and B to be determined at datum plane H
- (6) Controlling dimension: inches
- (7) Outline conforms to JEDEC® outline TO-263AB

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